

Schottky Rectifier, 3 A



PRODUCT SUMMARY			
Package	SMA		
I _{F(AV)}	3 A		
V_{R}	40 V		
V _F at I _F	0.46 V		
I _{RM}	20 mA at 125 °C		
T _J max.	150 °C		
Diode variation	Single die		
E _{AS}	6.0 mJ		

FEATURES

- Extremely low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Halogen-free according to IEC 61249-2-21 definition



- Surface mountable
- · Compact size
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS directive 2002/95/EC

APPLICATIONS

- Switching power supplies
- Meter protection
- Reverse protection for power input to PC board circuits
- · Battery isolation and charging
- Low threshold voltage diode
- Freewheeling or by-pass diode
- Low voltage clamp

DESCRIPTION

The VS-30MQ040-M3 Schottky rectifier is designed to be used for low power applications where a reverse voltage of 40 V is encountered and surface mountable is required.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	DC	3	A		
V_{RRM}		40	V		
I _{FSM}	t _p = 5 µs sine	330	А		
V _F	2 Apk, T _J = 125 °C	0.43	V		
T _J	Range	- 40 to 150	°C		

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-30MQ040-M3	UNITS
Maximum DC reverse voltage	V_{R}	40	V
Maximum working peak reverse voltage	V_{RWM}	40	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50% duty cycle at $T_L = 89 ^{\circ}$ C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		3	А
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	330	^
non-repetitive surge current See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	140	Α
Non-repetitive avalanche energy	E _{AS}	$T_{J} = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{A}, L = 12 \text{mH}$		6.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 1.0		Α	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		1 A	T _{.1} = 25 °C	0.42	V
Maximum forward voltage drop	V _{FM} ⁽¹⁾	3 A	11 = 23 0	0.51	
See fig. 1	V _{FM} (·)	1 A	T _J = 125 °C	0.34	
		3 A		0.46	
Maximum reverse leakage current		T _J = 25 °C	V Detect V	0.5	mΛ
See fig. 2	I _{RM}	$T_J = 125 ^{\circ}\text{C}$ $V_R = \text{Rated } V_R$	V _R = nateu V _R	20	mA mA
Threshold voltage	V _{F(TO)}	$T_{\rm J} = T_{\rm J} {\rm maximum}$ 0.26 64.6		0.26	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	C _T	V _R = 10 V _{DC} , T _J = 25 °C, test signal = 1 MHz		134	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

Note

 $^{^{(1)}}$ Pulse width = 300 μ s, duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approximate weight			0.07	g
Approximate weight			0.002	OZ.
Marking device		Case style SMA (similar D-64)	3	F

Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

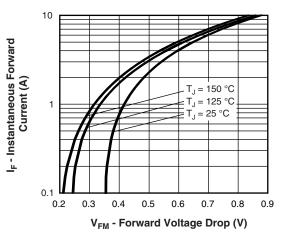


Fig. 1 - Maximum Forward Voltage Drop Characteristics

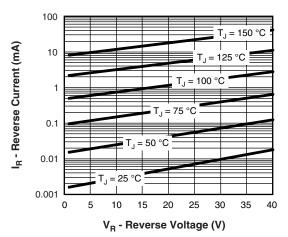


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

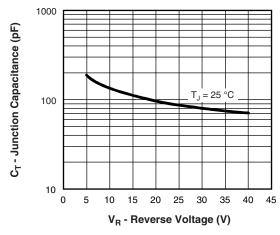
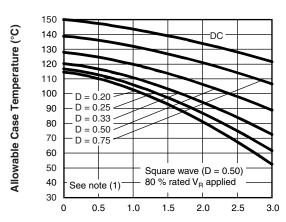


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



I_{F(AV)} - Average Forward Current (A)

Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

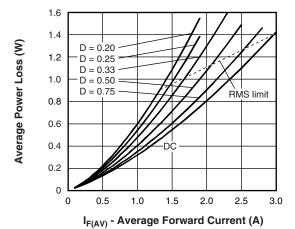


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

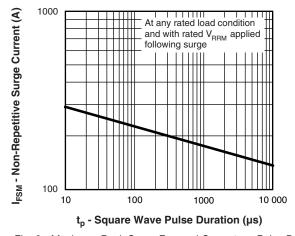


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

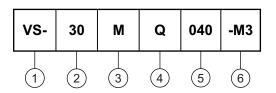
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product suffix

2 - Current rating

3 - M = SMA

4 - Q = Schottky "Q" series

Voltage rating (040 = 40 V)

6 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	ERRED P/N PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPT				
VS-30MQ040-M3/5AT	5AT	7500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?95400</u>			
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		



SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)



Mounting Pad Layout







Vishay

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